

BC848CW-7-F Datasheet



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DiGi Electronics Part Number BC848CW-7-F-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number BC848CW-7-F

Description TRANS NPN 30V 0.1A SOT323

Detailed Description Bipolar (BJT) Transistor NPN 30 V 100 mA 300MHz 2

00 mW Surface Mount SOT-323



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC848CW-7-F	Diodes Incorporated
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
30 V	600mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
20nA (ICBO)	420 @ 2mA, 5V
Power - Max:	Frequency - Transition:
200 mW	300MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
SC-70, SOT-323	SOT-323
Base Product Number:	
BC848	

Environmental & Export classification

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

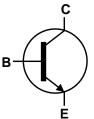
- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856W–BC858W
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

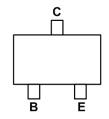
- Package: SOT323
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202. Method 208 @3.
- Weight: 0.006 grams (Approximate)







Device Symbol



Top View Pin-Out

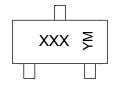
Ordering Information (Note 4)

Part Number	Dookogo	Marking	Dool Size (inches)	Packing		
Part Number	Package	warking	Reel Size (inches)	Qty.	Carrier	
BC846AW-7-F	SOT323	K1Q	7	3,000	Reel	
BC846BW-7-F	SOT323	K1R	7	3,000	Reel	
BC846BW-13-F	SOT323	K1R	13	10,000	Reel	
BC847AW-7-F	SOT323	K1Q	7	3,000	Reel	
BC847BW-7-F	SOT323	K1R	7	3,000	Reel	
BC847BW-13-F	SOT323	K1R	13	10,000	Reel	
BC847CW-7-F	SOT323	K1M	7	3,000	Reel	
BC847CW-13-F	SOT323	K1M	13	10,000	Reel	
BC848AW-7-F	SOT323	K1Q	7	3,000	Reel	
BC848BW-7-F	SOT323	K1R	7	3,000	Reel	
BC848CW-7-F	SOT323	K1M	7	3,000	Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



XXX = Product Type Marking Code
(Please See *Ordering Information*)
YM = Date Code Marking
Y or \(\overline{Y} = Year (ex: L = 2024)

Y or Y = Year (ex: L = 2024) M or \overline{M} = Month (ex: 2 = February)

Date Code Key

Year	2001	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	М	-	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteris	stic	Symbol	Value	Unit
	BC846AW/BW		80	
Collector-Base Voltage	BC847AW/BW/CW	V _{CBO}	50	V
	BC848AW/BW/CW		30	
	BC846AW/BW		65	
Collector-Emitter Voltage	BC847AW/BW/CW	V _{CEO}	45	V
	BC848AW/BW/CW		30	
Emitter-Base Voltage	BC846AW/BW BC847AW/BW/CW	VEBO	6	V
	BC848AW/BW/CW		5	
Continuous Collector Current	·	Ic	100	mA
Peak Collector Current		Ісм	200	mA
Peak Base Current		Івм	200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient	(Note 5)	Reja	625	°C/W
Thermal Resistance, Junction to Case	Reuc	115	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-65 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	C3
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Refer to JEDEC specification JESD22-A114, JESD22-C101 and JESD22-A115.

Thermal Characteristic and Derating Information

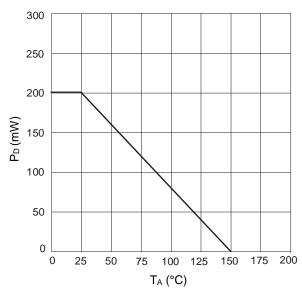


Figure 1. P_D v T_A



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

	Characte	ristic	Symbol	Min	Тур	Max	Unit	Test Condition	
		BC846AW/BW		80			V		
Collector-Base E	Breakdown Voltage	BC847AW/BW/CW	ВУсво	50	_	_		Ic = 100μA	
		BC848AW/BW/CW		30					
0.11	5 11 1/1	BC846AW/BW		65					
(Note 7)	r Breakdown Voltage	BC847AW/BW/CW	BVceo	45	_	_	V	Ic = 10mA	
(Note 1)		BC848AW/BW/CW		30					
Emitter-Base Bre	eakdown Voltage	BC846AW/BW BC847AW/BW/CW	BV _{EBO}	6	_		V	IE = 100μA	
		BC848AW/BW/CW		5					
DO 0		BC846AW/BC847AW/BC848AW		110	180	220			
Gain (Note 7)	OC Current Current Gain Group	BC846BW/BC847BW/BC848BW	hFE 200 420	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$	
Cam (Note 1)		BC847CW/BC848CW		520	800				
Collector Cutoff	Current		Ісво	_		20	nA	VcB = 30V	
Collector Cuton	Current					5	μΑ	$V_{CB} = 30V, T_A = +150^{\circ}C$	
Collector-Emitte	r Saturation Voltage (N	ote 7)	V _{CE(sat)}		90	250	mV	$I_C = 10mA, I_B = 0.5mA$	
Collector-Entitle	Toaturation voltage (N	ote 1)			200	600	1117	$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Tu	rn-on Voltage (Note 7)		VBE(on)	580	660	700	mV	Ic = 2mA, VcE = 5V	
Dase-Ellillel Tu	in-on voltage (Note 1)		VBE(on)	_	_	770	IIIV	Ic = 10mA, VcE = 5V	
Base-Emitter Sa	turation Voltage (Note	7)	V55()		700		mV	$I_C = 10mA, I_B = 0.5mA$	
Dase-Littiller Sa	turation voltage (Note	7)	V _{BE(sat)}		900		1110	$I_C = 100$ mA, $I_B = 5$ mA	
Output Capacita	nce		Cobo	_	3	4.5	pF	V _{CB} = 10V, f = 1.0MHz	
Transition Frequ	Transition Frequency		fτ	100	300		MHz	$V_{CE} = 5V$, $I_{C} = 10mA$ f = 100MHz	
Noise Figure			NF	_	_	10	dB	$\label{eq:CE_S} \begin{split} &\text{VCE} = 5\text{V}, \text{IC} = 200 \mu\text{A} \\ &\text{R}_{\text{S}} = 2\text{k}\Omega, \text{f} = 1\text{kHz} \\ &\Delta \text{f} = 200\text{Hz} \end{split}$	

Note:

7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

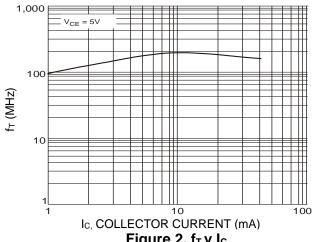


Figure 2. f_T v I_C

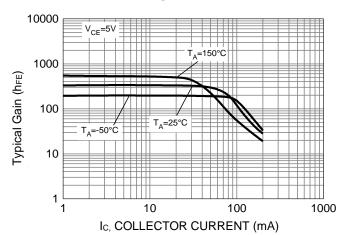


Figure 4. hFE v Ic (Band B Group Gain)

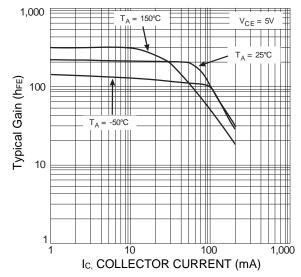


Figure 6. hFE v Ic (Band A Group Gain)

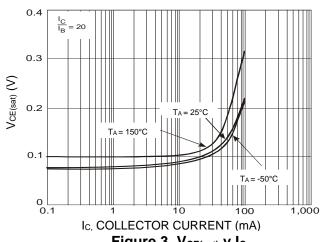


Figure 3. V_{CE(sat)} v I_C

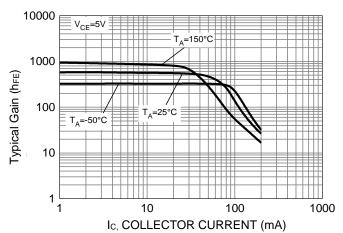


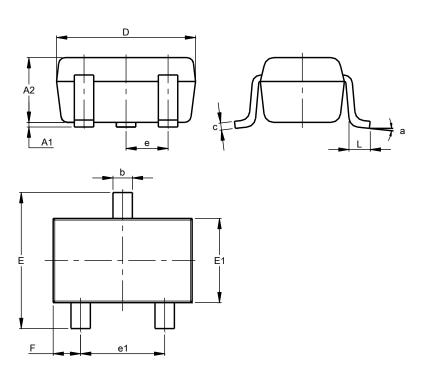
Figure 5. hFE v Ic (Band C Group Gain)



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

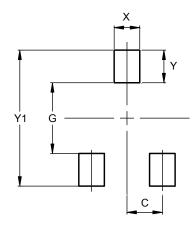


SOT323						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.25	0.40	0.30			
C	0.10	0.18	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C).650 B	SC			
e1	1.20	1.40	1.30			
F	0.375	0.475	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Υ	0.600
Y1	2.500



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